

Pb Free Plating Product

MURR1620FCT thru MURR16120FCT



16.0 Ampere Insulated Dual Doubler Polarity Ultra Fast Recovery Rectifiers

<p>Features</p> <ul style="list-style-type: none"> ThinkSemi latest&matured process FRD/FRED Low forward voltage drop High current capability Low reverse leakage current High surge current capability <p>Application</p> <ul style="list-style-type: none"> Automotive Inverters and Solar Inverters Car Audio Amplifiers and Sound Device Systems Plating Power Supply, Motor Control, UPS and SMPS etc. <p>Mechanical Data</p> <ul style="list-style-type: none"> Case: Isolated fully plastic ITO-220AB/TO-220F-3L package Epoxy: UL 94V-0 rate flame retardant Terminals: Solderable per MIL-STD-202 method 208 Polarity: As marked on diode body Mounting position: Any Weight: 2.0 gram approximately 	<p>ITO-220AB/TO-220F-3L Unit: inch(mm)</p> <p>① → ② → Case ③ → Case</p> <p>① → ② → Case ③ → Case</p> <p>① → ② → Case ③ → Case</p> <p>① → ② → Case ③ → Case</p> <p>Positive Common Cathode Prefix "MUR"</p> <p>Negative Common Anode Prefix "MURA"</p> <p>Doubler Doubler Polarity Prefix "MURR"</p> <p>Series Series Connection Prefix "MURL"</p>
--	--

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

PARAMETER	SYMBOL	MURR1620FCT	MURR1630FCT MURR1640FCT	MURR1660FCT	MURR1680FCT	MURR16100FCT	MURR16120FCT	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	200	400	600	800	1000	1200	V
Maximum RMS Voltage	VRMS	140	280	420	560	700	840	V
Maximum DC Blocking Voltage	VDC	200	400	600	800	1000	1200	V
Maximum Average Forward Rectified Current TC=125°C (Total Device 2x8.0A=16.0A)	IF(AV)	16.0						A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)(Per Diode/Per Leg)	IFSM	160						A
Maximum Instantaneous Forward Voltage @8.0A(Per Diode/Per Leg)	VF (Typical)	0.90-1.10	1.10-1.40	1.40-1.80	1.40-1.80			V
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	IR	5.0 500						µA µA
Maximum Reverse Recovery Time (Note1)	Trr	35-50			50-75			nS
Typical Junction Capacitance (Note 2)	CJ	80						pF
Typical Thermal Resistance (Note 3)	RθJC	3.0						°C/W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 to +175						°C

Note:(1)Reverse recovery test conditions IF = 0.5A, IR = 1.0A, Irr = 0.25A.
Note:(2)Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.
Note:(3)Thermal Resistance junction to case.

FIG.1 - FORWARD CURRENT DERATING CURVE

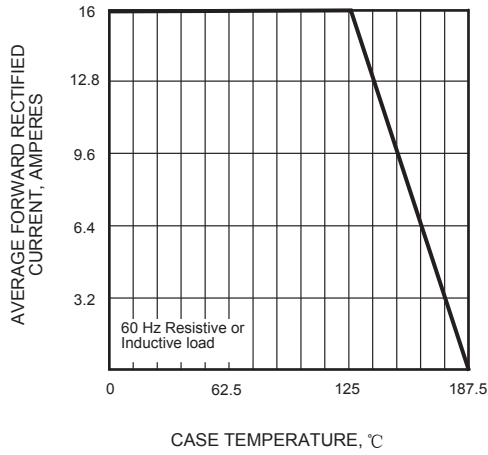


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

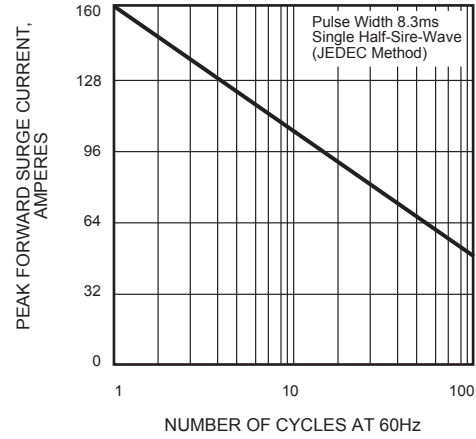


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

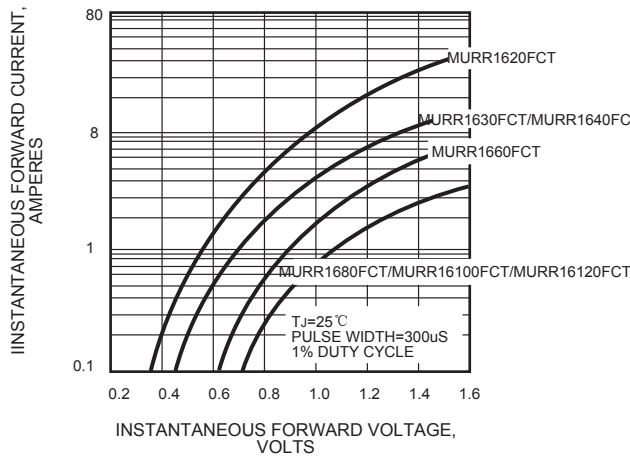


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

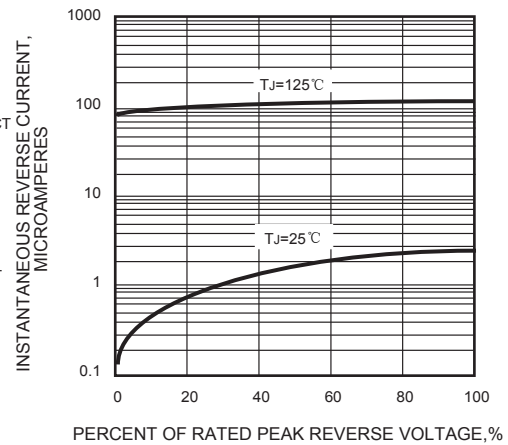


FIG.5 - TYPICAL JUNCTION CAPACITANCE

